The present amendment is in response to the Office Action mailed May

21, 2004, in which Claims 1 - 7, 9 - 17 and 17 - 23 were rejected. Applicant

has thoroughly reviewed the outstanding Office Action including the

Examiner's remarks and the reference cited therein. The following remarks

are believed to be fully responsive to the Office Action and, when coupled with

the amendments made herein, are believed to render all claims at issue

patentably distinguishable over the cited references.

Claims 1 - 6, 9 - 16, and 17 - 23 are amended herein. Claims 8 and 16

were previously cancelled. New Claims 24 through 26 are added.

Accordingly, Claims 1 - 6, 9 - 16, and 17 - 26 remain pending.

All the changes are made for clarification and are based on the

application and drawings as originally filed. It is respectfully submitted that

no new matter is added.

Applicant respectfully requests reconsideration in light of the above

amendments and the following remarks.

CLAIM REJECTIONS- 35 U.S.C. SECTION 112, 2nd PARAGRAPH

With respect to Paragraphs 1 and 2 of the Office Action, the Examiner

rejected Claims 1 through 23 that were rejected under 35 U.S.C. 112, second

paragraph, as being indefinite for failing to particularly point out and distinctly

claim the subject matter which applicant regards as the invention.

Applicant respectfully traverses this rejection.

The Examiner is of the opinion that the limitation of Claims 1, 9 and 17,

which refers to "a lens" "to measure said wafer and said datum slice" is

indefinite, for it is unclear as to how a lens measures.

Applicant has amended independent Claims 1, 7, and 17 for

clarification. According to the page 9 and lines 17 through 24 of the

specification of the application as filed disclosed that how to measure the

thickness of the wafer. The disclosure states: "Then, the stage 200 is moved

to the place under the lens 300 by using the transport device 270 to start

measuring the thickness of the wafer. The light us used to irradiate from

the lens 300 to the surface of the wafer 250 and the data, which is

returned from the light, is showed on the monitor 500. The thickness of

the wafer will be known by analyzing the data which is on the monitor

500." Thus, Applicant inserted the "the thickness of" before "said wafer and

said datum slice" in Claims 1, 9, and 17 to distinguish the limitation of the

above claims. In addition, Applicant has added new Claims 24 through 26 to

illustrate the "lens to measure the thickness of the wafer" according to the

specification at page 9 and lines 14 through 23.

Reconsideration and withdrawal of the rejections under 35 U.S.C.

Section 112, 2nd paragraph, are respectfully requested.

CLAIM REJECTIONS- 35 U.S.C. SECTION 103 (a)

With respect to Paragraphs 3 and 4 of the Office Action, the

Examiner rejected Claims 1-4, 6, 7, 9-12, 14, 15, 17, and 19-23 under 35

U.S.C. 103(a) as being unpatentable over Elliott et al (U.S. Patent No.

5,669,979) in view of Kilgore et al (U.S. Patent No. 6, 200,412) and Harwood

et al (U.S. Patent No. 5, 237,267) further in view of Rose et al (U.S. Patent No.

5, 931, 721).

With respect to Paragraphs 3 and 5 of the Office Action, the Examiner

rejected Claims 5, 13, and 18 under 35 U.S.C. 103(a) as being unpatentable

over Elliott et al (U.S. Patent No. 5,669,979) in view of Kilgore et al (U.S.

Patent No. 6,200,412) and Harwood et al (U.S. Patent No. 5,237,267) further

(U.S. Patent No. 6,272,768).

Applicant respectfully traverses these rejections.

Examiner is of the opinion that Elliott discloses the photoreactive

surface processing device. Kilgore et al taught the chuck and platens are

functional equivalents for wafer support. In addition, Harwood sets forth a

wafer probe station having auxiliary chucks taught that multiple chucks should

be used in order accommodate systems for calibration substrates. However,

Elliott is silent with respect to the second nozzle, but Rose discloses the

aerosol surface processing system has two nozzles opposing each other to

improve wafer-cleaning performance.

The combination of the disclosures of Elliott et al ('979), Kilgore et al

('412), Harwood et al ('267) and Rose ('721) is focused on the removal of

foreign material.

Elliott et al ('979) focuses on a laser beam of UV radiation that is

delivered at an acute angle to the surface of the substrate, the beam striking

the surface at a long and narrow reaction region. While the beam is sweeping

the surface, a flow reactant gas is provided at the reaction region so that the

gas is excited by the UV laser beam (Abstract). Elliott et al also disclosed the

reactant to react with the foreign material". The inducer gas may be a

member of the group consisting of NH₃, H₂, N₂O, and fluorocarbons. **The fluid**

may include a diluent gas (e.g., helium) to reduce the viscosity of the

reactant, or to reduce the ultraviolet absorption coefficient of the

reactant (e.g., a member of the group consisting of nitrogen, helium and

argon) (col. 2, lines 1-8). Furthermore, Elliott et al disclosed the input fluid, a

mixture of elemental gases, a gas-phase compound, a mixture of one or

more of these gases, or liquid is used to reduce or prevent the ablation

components of the foreign material in the cloud from re-depositing onto

the substrate surface by, e.g., reacting with the ablation components to

form simple gases ("reaction products," e.g., gases) or entraining the

ablation components in a gas flow away from the substrate. The

formation of the reaction products is generally associated with the generation

of heat and light (col. 5, lines 50-60).

Kilgore et al ('412) discloses a plasma of hydrogen or a

hydrogen—oxygen mixture that is used to remove fluorine-bearing residues

from the surfaces of the reaction chamber following the clean cycle (col.

2, lines 44-46).

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Rose et al ('721) discloses removing foreign material from the surface

of a substrate by directing a high velocity aerosol of at least partially frozen

particles against the foreign material to be removed (Abstract). Rose ('721)

also discloses this method comprising the steps of: generating a flow of a gas

having a temperature above the freezing point of the aerosol particles for

entraining the aerosol of at least partially frozen particles; entraining the

aerosol particles in the gas; accelerating the gas to a t least sonic velocity;

and "delivering the entrained aerosol particles to foreign material to be

removed from the surface of the substrate" (col. 3, lines 22-27).

Nevertheless, regarding the amended claims, which disclosed a

measuring system of a gas-stream environment, the measuring system

focuses on the measuring the thickness of the wafer by lens. The present

invention disclosed the "lens locating above the stage to measure the

thickness of the wafer and the datum slice". The present invention also

does not utilize the laser beam that used to react with foreign material

on the surface of substrate. However, the purpose of the combination of the

disclosures of Elliott et al ('979), Kilgore et al ('412), Harwood et al ('267) and

Rose ('721) is to remove the foreign material on the surface of the

surface. Therefore, the enablement and the objective are different between

the present invention and the combination of the cited disclosures. Thus, the

rejection cannot achieve the present invention.

In addition, the Examiner is of the opinion that the combination of the

disclosures of Elliott et al ('979), Kilgore et al ('412), Harwood et al ('267) and

Danese ('768) disclosed everything as above (as Claims 1, 9, 17). However,

Elliott et al are silent with respect to a venturi structure for the mechanical

pump. Danese ('768) discloses an apparatus for treating something in UV

light that taught the venturei pump are typical vacuum pumps for

withdrawing fluids.

The amended claims disclose a measuring system of a gas-stream. As

with the above statements, the objective of the present invention is to

measure the thickness of the wafer by use of a lens. According to the

disclosure of Danese ('768), "the UV source is configured to deliver the

ultraviolet light through the vapor to process the object (Abstract). Thus,

the objective of the combination of the disclosure of above reference

citations is to remove the foreign material by "UV light (or UV source)".

The disclosure of the present did invention did not utilize the "UV light" to

treat the surface of the substrate. According to the amended claims, the

present invention utilized the lens to measure the thickness of the wafer.

Therefore, the enablement and objective are different between the present

invention and the combination of the disclosure of above reference citations.

Thus, the combination of the disclosures of Elliott et al ('979), Kilgore et

al('412), Harwood et al ('267), and Daese ('768) cannot achieve the present

invention.

Reconsideration and withdrawal of the rejections under 35 U.S.C.

Section 103(a) are respectfully requested.

CONCLUSION

In light of the above amendments and remarks, Applicant respectfully

submits that all pending Claims 1-7, 9-15, and 17-23 as currently presented

are in condition for allowance. If, for any reason, the Examiner disagrees,

please call the undersigned attorney at 248-433-7552 in an effort to resolve

any matter still outstanding before issuing another action. The undersigned

attorney is confident that any issue which might remain can readily be worked

out by telephone.

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Applicant respectfully requests that a timely Notice of Allowance be

issued in this case.

Respectfully submitted,

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Dated: August 23, 2004

TTM/hs